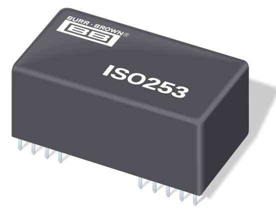
BURR - BROWN ®

ISO253



Precision, Powered, Three-Port Isolated BUFFER AMPLIFIER

FEATURES

- **RATED**
  1500Vrms Continuous
  2500Vrms for One Minute
- **100% TESTED FOR PARTIAL DISCHARGE**
- **LOW NONLINEARITY: ±0.01% typ**
- **INPUT PROTECTED TO ±100V**
- **BIPOLAR OPERATION: V_O = ±10V**
- **SYNCHRONIZATION CAPABILITY**
- **28-PIN PLASTIC DIP: 0.6" Wide**

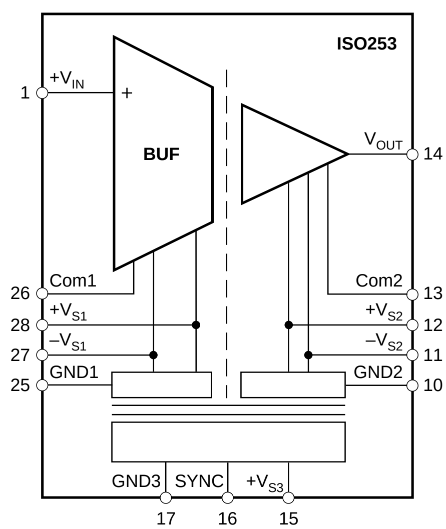
APPLICATIONS

- **INDUSTRIAL PROCESS CONTROL**
  Transducer Isolator, Thermocouple Isolator, RTD Isolator, Pressure Bridge Isolator, Flow Meter Isolator
- **POWER MONITORING**
- **MEDICAL INSTRUMENTATION**
- **ANALYTICAL MEASUREMENTS**
- **DATA ACQUISITION**
- **TEST EQUIPMENT**
- **GROUND LOOP ELIMINATION**

DESCRIPTION

ISO253 is a precision three-port isolated buffer amplifier incorporating a novel duty cycle modulation-demodulation technique and has excellent accuracy. The input is protected to withstand ±100V without damage. The signal is transmitted digitally across a differential capacitive barrier. With digital modulation the barrier characteristics do not affect signal integrity. This results in excellent reliability and good high frequency transient immunity across the barrier. The DC/DC converter, amplifier and barrier capacitors are housed in a plastic DIP.

This amplifier is easy to use as no external components are required. A power supply range of 11V to 18V makes this amplifier ideal for a wide range of applications.



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SPECIFICATIONS

At T_A = +25°C, V_{S3} = 15V, R_L = 2kΩ, and 220nF capacitors on all generated supplies, unless otherwise noted.

PARAMETER	CONDITIONS	ISO253P MIN	ISO253P TYP	ISO253P MAX	UNITS
ISOLATION					
Voltage Rated Continuous:					
AC	T_{MIN} to T_{MAX}	1500			Vrms
100% Test (AC 50Hz)	1s; Partial Discharge ≤ 5pC	2500			Vrms
Rated One Min		2500			Vrms
Isolation-Mode Rejection					
DC			120		dB
AC 50Hz	1500Vrms		95		dB
Barrier Impedance			10^{14} || 2		Ω || pF
Leakage Current	VISO = 240Vrms, 50Hz		1.4	2	μArms
GAIN					
Nominal Gain			1		V/V
Gain Error			0.15	±0.3	%
Gain vs Temperature			15		ppm/°C
Nonlinearity			0.01	±0.1	%
INPUT OFFSET VOLTAGE					
Initial Offset				±100	mV
vs Temperature			150		μV/°C
vs Supply			1		mV/V
INPUT					
Voltage Range		±10	±15		V
Resistance			200		kΩ
OUTPUT					
Voltage Range		±10			V
Current Drive		±5			mA
Capacitive Load Drive			0.1		μF
Ripple Voltage			25		mVp-p
FREQUENCY RESPONSE					
Small Signal Bandwidth			50		kHz
Slew Rate			0.25		V/μs
Settling Time, 0.1%			50		μs
POWER SUPPLIES					
Rated Voltage			15		V
Voltage Range		11		18	V
Quiescent Current		25	40	55	mA
Rated Output Voltage	No Load	13	14.5		V
	50mA Load On Two Supplies	12	13.2	16	V
Load Regulation			28		mV/mA
Line Regulation			1		V/V
SYNC Frequency		1		1.4	MHz
Output Voltage Ripple			50		mV
TEMPERATURE RANGE					
Operating		–40		85	°C
Storage		–40		85	°C

ABSOLUTE MAXIMUM RATINGS

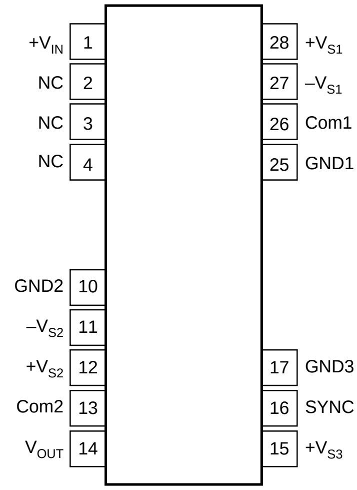
Supply Voltage	+18V
V_{IN}, Analog Input Voltage Range	±100V
Com1 to GND1	±1V
Com2 to GND2	±1V
Continuous Isolation Voltage:	1500Vrms
	2500Vrms one min
IMV, dv/dt	20kV/µs
Junction Temperature	150°C
Storage Temperature	–40°C to +85°C
Lead Temperature (soldering, 10s)	+300°C
Output Short Duration	Continuous to Common

ELECTROSTATIC DISCHARGE SENSITIVITY

Any integrated circuit can be damaged by ESD. Burr-Brown recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet published specifications.

PIN CONFIGURATION



PACKAGE INFORMATION

PRODUCT	PACKAGE	PACKAGE DRAWING NUMBER(1)
ISO253P	28-Pin Plastic DIP	335

NOTE: (1) For detailed drawing and dimension table, please see end of data sheet, or Appendix C of Burr-Brown IC Data Book.

ORDERING INFORMATION

PRODUCT	PACKAGE
ISO253P	28-Pin Plastic DIP

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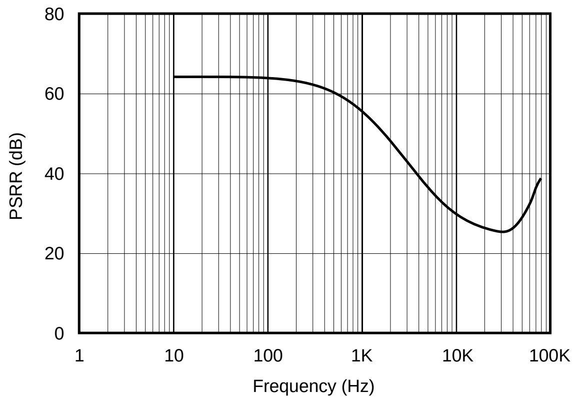
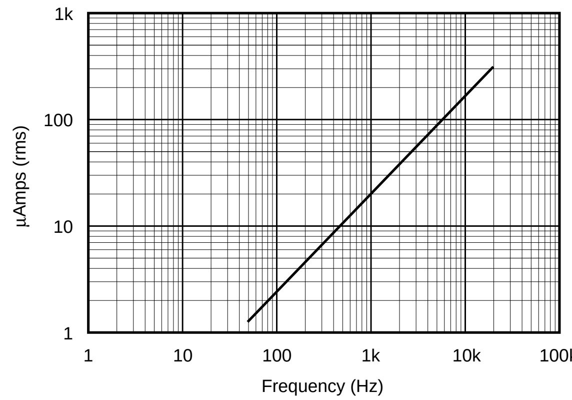
TYPICAL PERFORMANCE CURVES

At $T_A = +25°C$, $+V_{S3} = 15V$, $R_L = 2kΩ$, and 220nF capacitors on all generated supplies, unless otherwise noted.

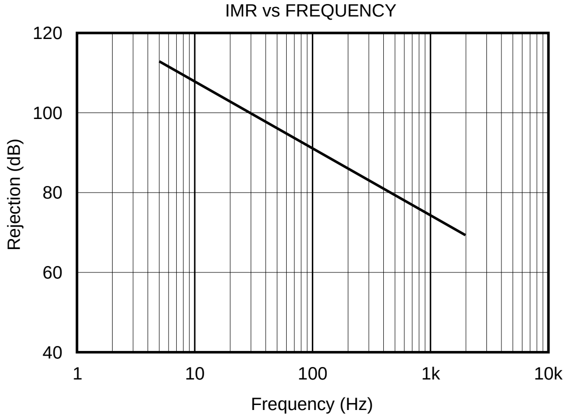
PSRR vs FREQUENCY



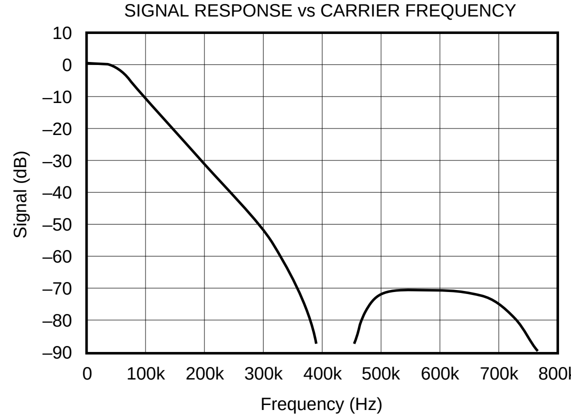
ISOLATION LEAKAGE CURRENT vs FREQUENCY
(V = 240Vrms)



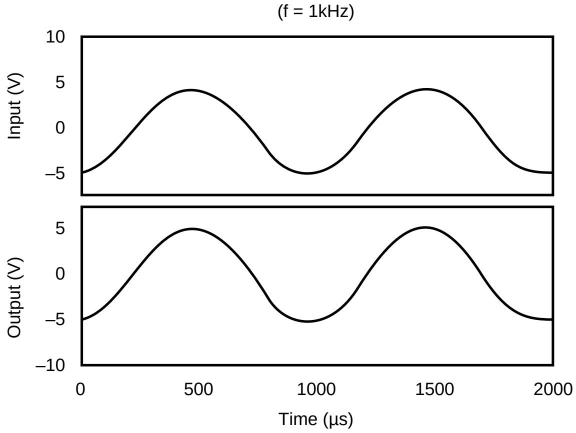
IMR vs FREQUENCY



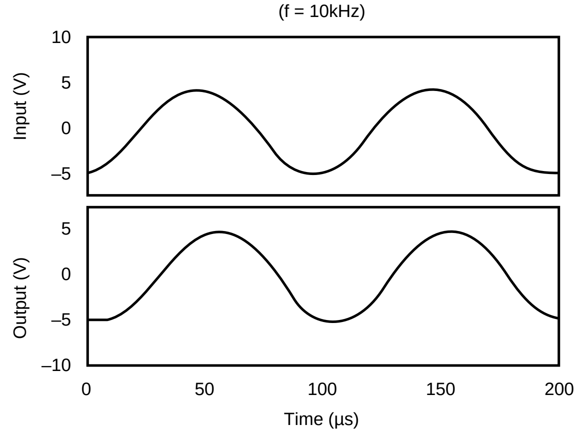
SIGNAL RESPONSE vs CARRIER FREQUENCY



SINE RESPONSE
(f = 1kHz)



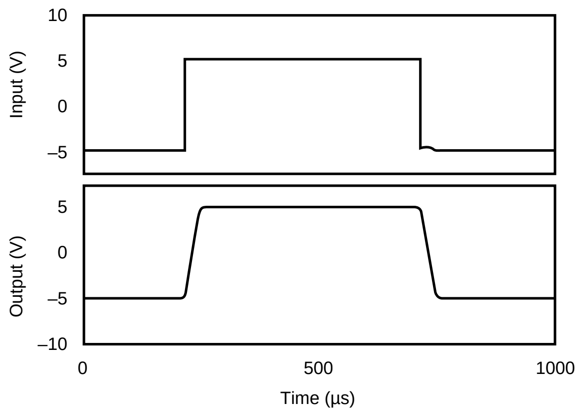
SINE RESPONSE
(f = 10kHz)



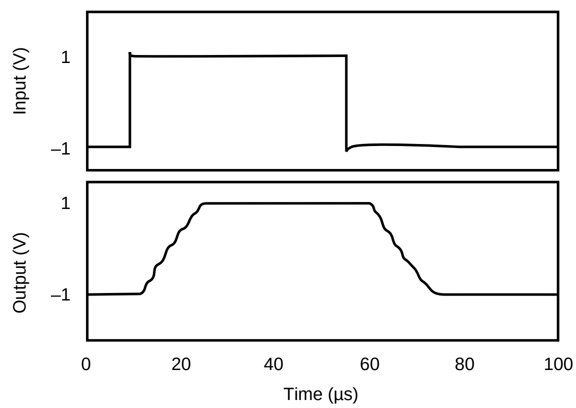
TYPICAL PERFORMANCE CURVES (CONT)

At T_A = +25°C, $+V_{S3}$ = 15V, R_L = 2kΩ, and 220nF capacitors on all generated supplies, unless otherwise noted.

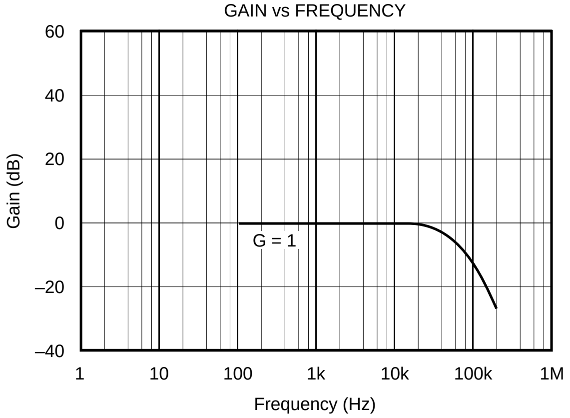
PULSE RESPONSE
(f = 1kHz)



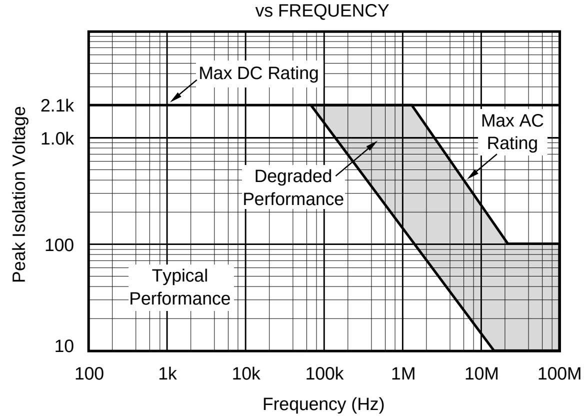
PULSE RESPONSE
(f = 10kHz)



GAIN vs FREQUENCY



ISOLATION MODE VOLTAGE
vs FREQUENCY



BASIC OPERATION

ISO253 is a precision, powered, three-port isolated buffer amplifier. The input and output sections are galvanically isolated by matched and EMI shielded capacitors built into the plastic package. The DC/DC converter input is also galvanically isolated from both the input and output supplies.

SIGNAL AND POWER CONNECTIONS

Figure 1 shows proper power and signal connections. The power supply input pin $+V_{S3}$ should be bypassed with a 2.2µF tantalum capacitor and the outputs V_{S1} and V_{S2} with 220nF ceramic capacitors located as close to the amplifier as possible. All ground connections should be run independently to a common point. Signal Common on both input and output sections provide a high-impedance point for sensing signal ground in noisy applications. Com1 and Com2 must have a path to ground for signal current returns and should be maintained within ±1V of GND1 and GND2 respectively.

INPUT PROTECTION

The input of the buffer amplifier is protected for voltages up to ±100V. The input is a 200kΩ resistor to the summing node of the input amplifier.

DC/DC CONVERTER

ISO253 provides a reliable solution to the need for integral power. The high isolation rating being achieved by careful design and attention to the physical construction of the transformer. In addition to the high dielectric strength a low leakage coating increases the isolation voltage range. The soft start oscillator/driver design eliminates high inrush currents during turn-on. Input current sensing protects both the converter and the load from possible thermal damage during a fault condition. The DC/DC converter is synchronized to the amplifier and when multiple ISO253's are used, each channel can be synchronized via the SYNC pin.

The DC/DC converter consists of a free-running oscillator, control and switch driver circuitry, MOSFET switches, a transformer, rectifier diodes and filter capacitors all contained within the ISO253 package. The control circuitry consists of current limiting, soft start and synchronization features. In instances where several ISO253's are used in a system, beat frequencies developed between the ISO253's are a potential source of low frequency noise in the supply and ground paths. This noise may couple into the signal path and can be avoided by synchronizing the individual ISO253's together by tying the SYNC pins together or using the circuit in Figure 2 to drive the SYNC pins from an external source.

When connecting up to eight ISO253's without a driver the unit with the highest natural frequency will determine the synchronized running frequency. The SYNC pin is sensitive to capacitive loading: 150pF or less is recommended. If unused, the SYNC pin should be left open. Avoid shorting the SYNC pin directly to ground or supply potentials; otherwise damage may result.

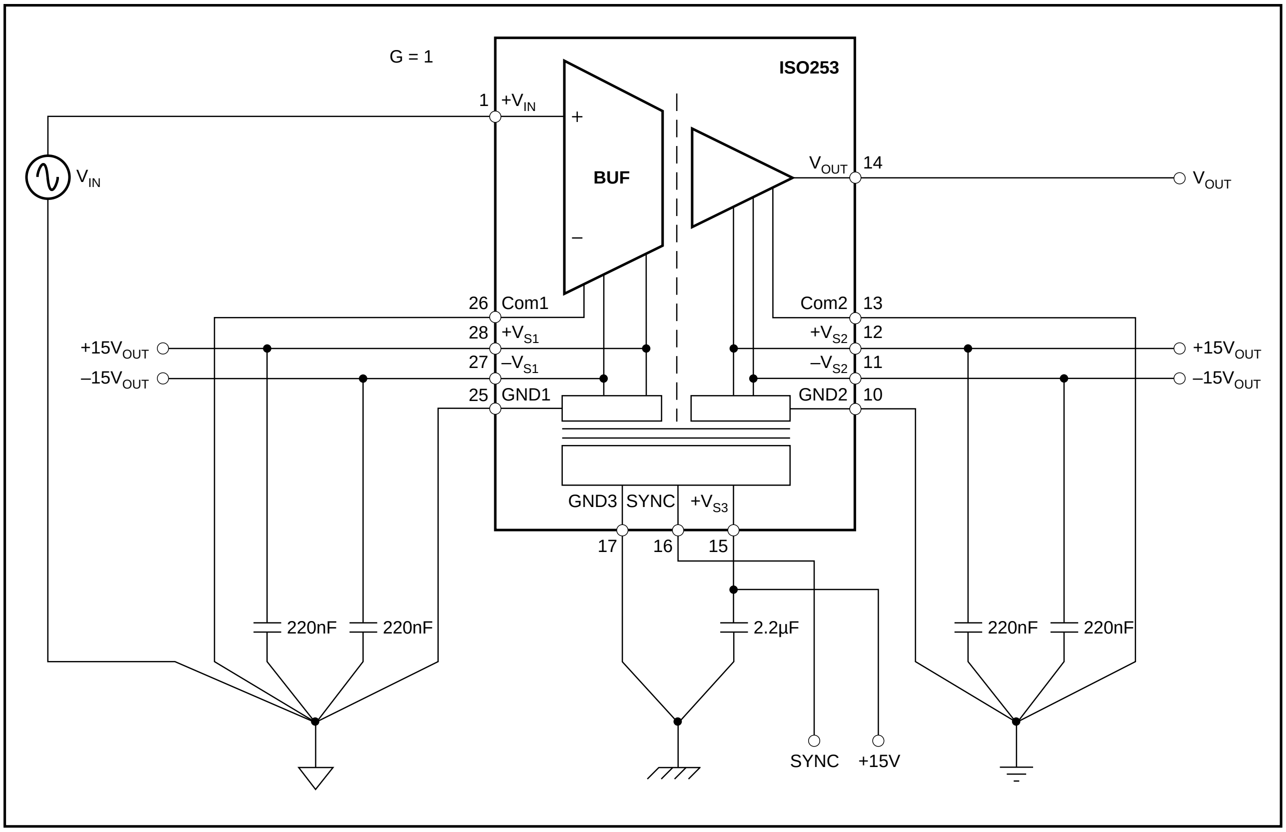


FIGURE 1. Basic Connections.

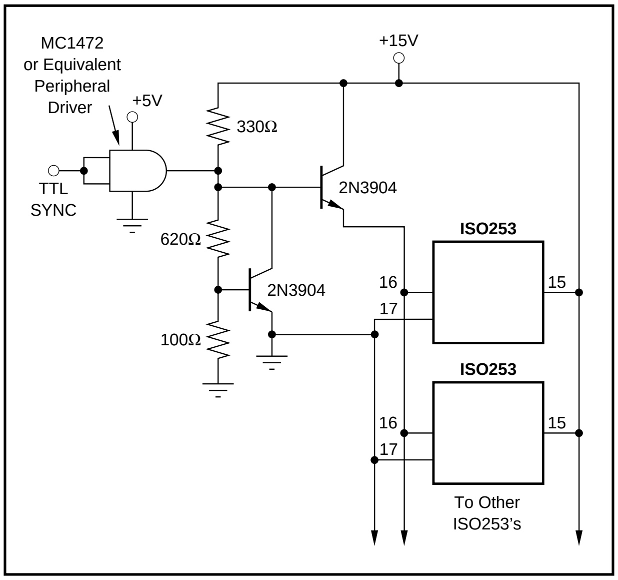


FIGURE 2. External SYNC drive.

Soft start circuitry protects the MOSFET switches during startup. This is accomplished by holding the gate-to-source voltage of both MOSFET switches low until the free-running oscillator is fully operational. In addition, soft start circuitry and input current sensing also protects the switches. This current limiting keeps the MOSFET switches operating in their safe operating area under fault conditions or excessive loads. When either of these conditions occur, the peak input current exceeds a safe limit. The result is an approximate 5% duty cycle, 300µs drive period to the MOSFET switches. This protects the internal MOSFET switches as well as the external load from any thermal damage. When the fault or excessive load is removed, the converter resumes normal operation. A delay period of approximately 50µs incorporated in the current sensing circuitry allows the output filter capacitors to fully charge after a fault is removed. This delay period corresponds to a filter capacitance of no more than 1µF at either of the output pins. This provides full protection of the MOSFET switches and also sufficiently filters the output ripple voltage. The current sensing circuitry is designed to provide thermal protection for the MOSFET switches over the operating temperature range as well. When these conditions are exceeded, the unit will go into its shutdown mode.

OUTPUT CURRENT RATINGS

The total current which can be drawn from each output supply on the ISO253 is a function of the total power drawn from all outputs. For example if three outputs are not used then maximum current can be drawn from one output. In all cases, the total maximum current that can be drawn from any combination of outputs is:

$$|I_{1+}| + |I_{1-}| + |I_{2+}| + |I_{2-}| \leq 50\text{mA}$$

$+V_{S3}$, GND3

The waveform of the ground return current is an 800kHz sawtooth. A capacitor between $+V_{S3}$ and GND3 provides a bypass for the AC portion of this current. The power should never be instantaneously interrupted to the ISO253 (i.e., a break in the line to $+V_{S3}$ either by accidental or switch means.) Normal power down of the $+V_{S3}$ supply is not considered instantaneous. Should a rapid break in input power occur the internal transformers voltage will rapidly rise to maintain current flow and may cause internal damage to the ISO253.

SYNCHRONIZED OPERATION

ISO253 can be synchronized to an external signal source. This capability is useful in eliminating troublesome beat frequencies in multi-channel systems and in rejecting AC signals and their harmonics. To use this feature, tie all sync pins together or apply an external signal to the SYNC pin. ISO253 can be synchronized to an external oscillator over the range 1-1.4MHz (this corresponds to a modulation frequency of 500kHz to 700kHz as SYNC is internally divided by 2).

CARRIER FREQUENCY CONSIDERATIONS

ISO253 amplifiers transmit the signal across the ISO-barrier by a duty-cycle modulation technique. This system works like any linear amplifier for input signals having frequencies below one half the carrier frequency, f_C. For signal frequencies above $f_C/2$, the behavior becomes more complex. The "Signal Response vs Carrier Frequency" performance curve describes this behavior graphically. The upper curve illustrates the response for input signals varying from DC to $f_C/2$. At input frequencies at or above $f_C/2$, the device generates an output signal component that varies in both amplitude and frequency, as shown by the lower curve. The lower horizontal scale shows the periodic variation in the frequency of the output component. Note that at the carrier frequency and its harmonics, both the frequency and amplitude of the response go to zero. These characteristics can be exploited in certain applications.

It should be noted that for the ISO253, the carrier frequency is nominally 400kHz and the –3dB point of the amplifier is 50kHz. Spurious signals at the output are not significant under these circumstances unless the input signal contains significant components above 200kHz.

When periodic noise from external sources such as system clocks and DC/DC converters is a problem, ISO253 can be used to reject this noise. The amplifier can be synchronized to an external frequency source, f_{EXT}, placing the amplifier response curve at one of the frequency and amplitude nulls indicated in the "Signal Response vs Carrier Frequency" performance curve.

ISOLATION MODE VOLTAGE

Isolation Mode Voltage (IMV) is the voltage appearing between isolated grounds GND1 and GND2. The IMV can induce errors at the output as indicated by the plots of IMV vs Frequency. It should be noted that if the IMV frequency exceeds $f_C/2$, the output will display spurious outputs in a manner similar to that described above, and the amplifier response will be identical to that shown in the "Signal Response vs Carrier Frequency" performance curve. This occurs because IMV-induced errors behave like input-referred error signals. To predict the total IMR, divide the isolation voltage by the IMR shown in "IMR vs Frequency" performance curve and compute the amplifier response to this input-referred error signal from the data given in the "Signal Response vs Carrier Frequency" performance curve. Due to effects of very high-frequency signals, typical IMV performance can be achieved only when dV/dT of the isolation mode voltage falls below 1000V/µs. For convenience, this is plotted in the typical performance curves for the ISO253 as a function of voltage and frequency for sinusoidal voltages. When dV/dT exceeds 1000V/µs but falls below 20kV/µs, performance may be degraded. At rates of change above 20kV/µs, the amplifier may be damaged, but the barrier retains its full integrity. Lowering the power supply voltage below 15V may decrease the dV/dT to 500V/µs for typical performance, but the maximum dV/dT of 20kV/µs remains unchanged.

Leakage current is determined solely by the impedance of the barrier and transformer capacitance and is plotted in the "Isolation Leakage Current vs Frequency" curve.

ISOLATION VOLTAGE RATINGS

Because a long-term test is impractical in a manufacturing situation, the generally accepted practice is to perform a production test at a higher voltage for some shorter time. The relationship between actual test voltage and the continuous derated maximum specification is an important one.

Historically, Burr-Brown has chosen a deliberately conservative one: VTEST = (2 x ACrms continuous rating) + 1000V for 10 seconds, followed by a test at rated ACrms voltage for one minute. This choice was appropriate for conditions where system transients are not well defined.

Recent improvements in high-voltage stress testing have produced a more meaningful test for determining maximum permissible voltage ratings, and Burr-Brown has chosen to apply this new technology in the manufacture and testing of the ISO253.

Partial Discharge

When an insulation defect such as a void occurs within an insulation system, the defect will display localized corona or ionization during exposure to high-voltage stress. This ionization requires a higher applied voltage to start the discharge and lower voltage to maintain it or extinguish it once started. The higher start voltage is known as the inception voltage, while the extinction voltage is that level of voltage stress at which the discharge ceases. Just as the total insulation system has an inception voltage, so do the individual voids. A voltage will build up across a void until its inception voltage is reached, at which point the void will ionize, effectively shorting itself out. This action redistributes electrical charge within the dielectric and is known as partial discharge. If, as is the case with AC, the applied voltage gradient across the device continues to rise, another partial discharge cycle begins. The importance of this phenomenon is that, if the discharge does not occur, the insulation system retains its integrity. If the discharge begins, and is allowed to continue, the action of the ions and electrons within the defect will eventually degrade any organic insulation system in which they occur. The measurement of partial discharge is still useful in rating the devices and providing quality control of the manufacturing process. The inception voltage for these voids tends to be constant, so that the measurement of total charge being redistributed within the dielectric is a very good indicator of the size of the voids and their likelihood of becoming an incipient failure. The bulk inception voltage, on the other hand, varies with the insulation system, and the number of ionization defects and directly establishes the absolute maximum voltage (transient) that can be applied across the test device before destructive partial discharge can begin. Measuring the bulk extinction voltage provides a lower, more conservative voltage from which to derive a safe continuous rating. In production, measuring at a level somewhat below the expected inception voltage and then de-rating by a factor related to expectations about system transients is an accepted practice.

Partial Discharge Testing

Not only does this test method provide far more qualitative information about stress-withstand levels than did previous stress tests, but it provides quantitative measurements from which quality assurance and control measures can be based. Tests similar to this test have been used by some manufacturers, such as those of high-voltage power distribution equipment, for some time, but they employed a simple measurement of RF noise to detect ionization. This method was not quantitative with regard to energy of the discharge, and was not sensitive enough for small components such as isolation amplifiers. Now, however, manufacturers of HV test equipment have developed means to quantify partial discharge. VDE in Germany, an acknowledged leader in high-voltage test standards, has developed a standard test method to apply this powerful technique. Use of partial discharge testing is an improved method for measuring the integrity of an isolation barrier.

To accommodate poorly-defined transients, the part under test is exposed to voltage that is 1.6 times the continuous-rated voltage and must display less than or equal to 5pC partial discharge level in a 100% production test.

APPLICATIONS

The ISO253 isolation amplifiers are used in three categories of applications:

- Accurate isolation of signals from high voltage ground potentials
- Accurate isolation of signals from severe ground noise and
- Fault protection from high voltages in analog measurements

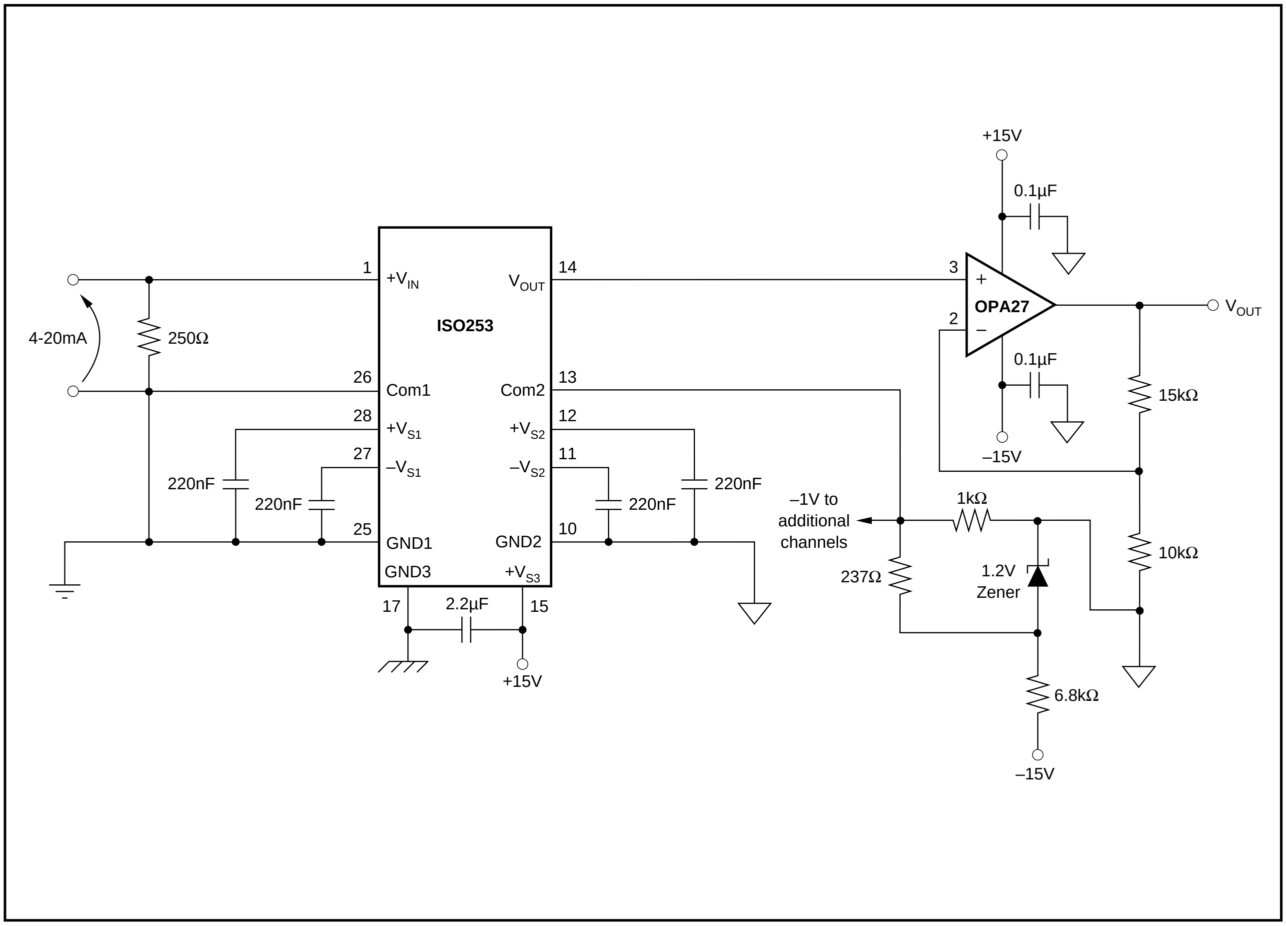


FIGURE 3. Process Current Input Isolator with Offset.